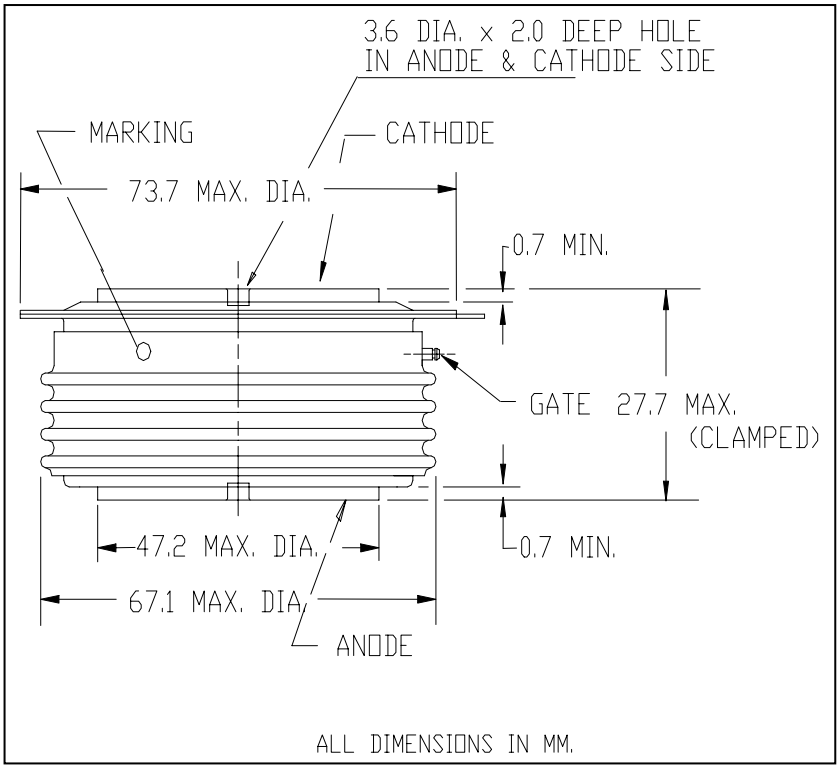
Powerex, Inc., 200 Hillis Street, Youngwood, Pennsylvania 15697-1800 (724)925-7272

C702

Phase Control Thyristor

1000 Amperes 3200 Volts



The C702 is a medium voltage, high current disc pack SCR employing a Bar gate, amplifying gate structure. This amplifying gate design allows the SCR to be reliably operated at high di/dt and high dv/dt conditions in phase control applications.

FEATURES:

- Low On-State Voltage
- High di/dt Capability
- High dv/dt Capability
- Hermetic Ceramic Package
- Excellent Surge and I^2t Ratings

APPLICATIONS:

- DC Power Supplies
- Motor Controls
- AC Soft-Starters

ORDERING INFORMATION

Select the complete Part Number using the table below.
EXAMPLE: C702CB is a 3200V-1000A SCR with 200ma IGT and 12 inch gate and cathode potential leads.

PART	Voltage Rating	Voltage Code	Current Rating
	V_{DRM}-V_{RRM}		I_{tavg}
C702	2400V	**LD**	1000A
	2600V	**LM**	
	2800V	**LN**	
	3000V	**CP**	
	3200V	**CB**	

Revised: 5/11/2004

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Absolute Maximum Ratings

Characteristic	Symbol	Rating	Units
Repetitive Peak Voltage	V_{DRM}-V_{RRM}	3200	Volts
Non-repetitive Transient Peak Reverse Voltage	V_{RSM}	V_{RRM} + 100	Volts
Average On-State Current, T_C=74°C	$I_{T(Avg.)}$	1000	A
RMS On-State Current, T_C=74°C	$I_{T(RMS)}$	1571	A
Average On-State Current, T_C=55°C	$I_{T(Avg.)}$	1220	A
RMS On-State Current, T_C=55°C	$I_{T(RMS)}$	1916	A
Peak One Cycle Surge Current, 60Hz, V_R=0V	I_{TSM}	21,500	A
Peak One Cycle Surge Current, 50Hz, V_R=0V	I_{TSM}	20,500	A
Fuse Coordination I^2t, 60Hz	I^2t	1.93E+06	A^2s
Fuse Coordination I^2t, 50Hz	I^2t	2.10E+06	A^2s
Critical Rate-of-Rise of On-State Current Repetitive	di/dt	100	A/us
Critical Rate-of-Rise of On-State Current Non-Repetitive	di/dt	300	A/us
Peak Gate Power, 100us	P_{GM}	16	Watts
Average Gate Power	$P_{G(avg)}$	5	Watts
Operating Temperature	Tj	-40 to+125	°C
Storage Temperature	$T_{Stg.}$	-50 to+150	°C
Approximate Weight		1	lb
		0.45	Kg
Mounting Force		5500-6000	lbs
		24.5 - 26.7	Knewtons

Electrical Characteristics, Tj=25°C unless otherwise specified

Characteristic	Symbol	Test Conditions	Rating min	Rating typ	Rating max	Units
Repetitive Peak Forward Leakage Current	I_{DRM}	Tj=125°C, V_{DRM}=Rated			150	ma
Repetitive Peak Reverse Leakage Current	I_{RRM}	Tj=125°C, V_{RRM}=Rated			150	ma
Peak On-State Voltage	V_{TM}	Tj=125°C, I_{TM}=2000A			1.85	V
V_{TM} Model, Low Level	V_0	Tj=125°C			0.944	V
VTM = V_O + r•I_{TM}	r	15% I_{TM} - π•I_{TM}			4.25E-04	Ω
V_{TM} Model, High Level	V_0	Tj=125°C			1.18	V
VTM = V_O + r•I_{TM}	r	π•I_{TM} - I_{TSM}			3.49E-04	Ω
V_{TM} Model, 4-Term	A	Tj=125°C			0.363	
V_{TM}= A + B•Ln(I_{TM}) +	B	15%I_{TM} - I_{TSM}			0.108	
C•(I_{TM}) + D•(I_{TM})^{½}	C				3.42E-04	
	D				-8.33E-04	
Turn-On Delay Time	t_d	V_D = 0.5•V_{DRM} Gate Drive: 40V - 20Ω		2.5		us
Turn-Off Time	tq	Tj=125°C dv/dt = 20V/us to 80% V_{DRM}		400		us
$dv/dt_{(Crit)}$	dv/dt	Tj=125°C Exp. Waveform V_D =80% Rated	400			V/us
Gate Trigger Current	I_{GT}	Tj=25°C V_D = 12V	30	100	200	ma
Gate Trigger Voltage	V_{GT}		0.8	2.0	4.5	V
Peak Reverse Gate Voltage	V_{GRM}				5	V

Thermal Characteristics

Characteristic	Symbol	Test Conditions	Rating min	Rating typ	Rating max	Units
Thermal Resistance						
Junction to Case	$R\Theta_{jc}$	Double side cooled		0.021	0.023	°C/Watt
Case to Sink	$R\Theta_{cs}$	Double side cooled		0.004	0.006	°C/Watt
Thermal Impedance Model	$Z\Theta_{jc}$	Double side cooled				

$$Z\Theta_{jc}(t) = \Sigma(A(N)\bullet(1-\exp(-t/Tau(N))))$$ where:

N =	1	2	3	4
A(N) =	7.26E-04	1.58E-03	4.55E-03	1.62E-02
Tau(N) =	4.49E-05	8.21E-03	8.84E-02	1.31E+00

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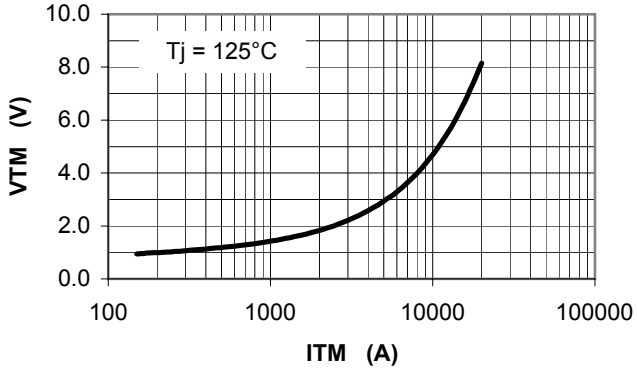
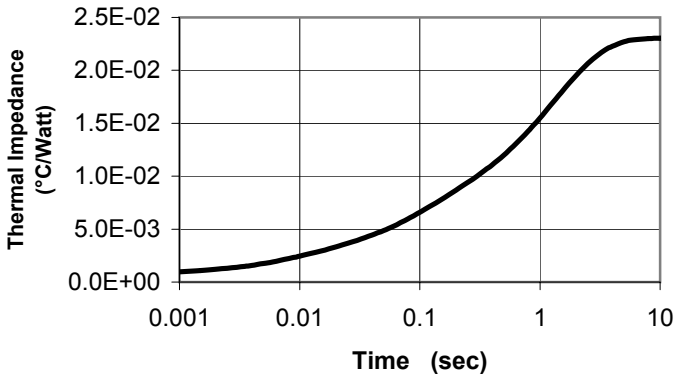
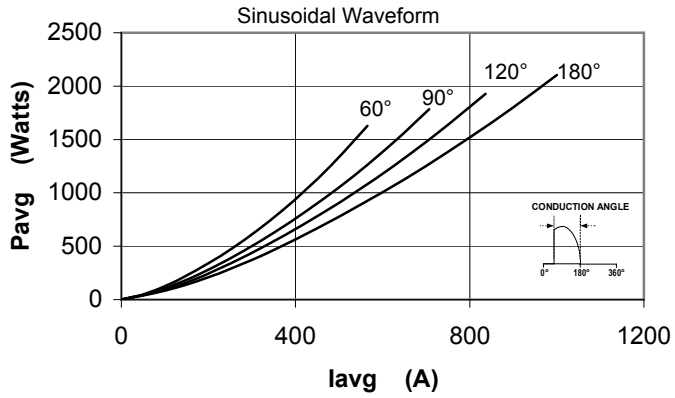
Maximum On-State Voltage Drop



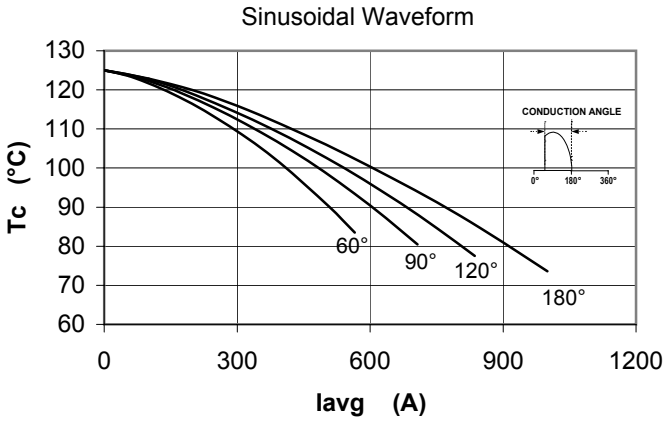
MAXIMUM TRANSIENT THERMAL IMPEDANCE



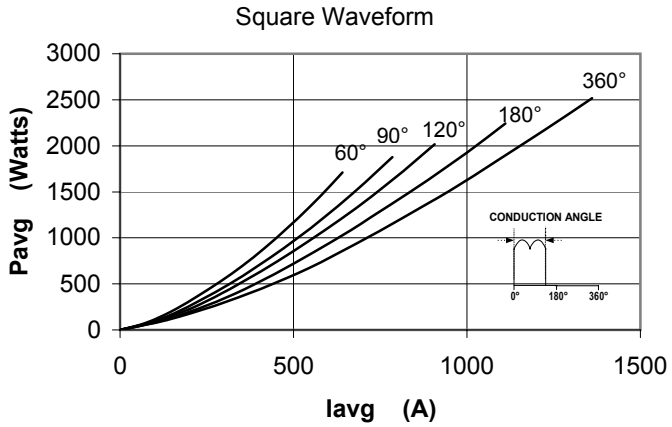
Maximum On-State Power Dissipation



Maximum Allowable Case Temperature



Maximum On-State Power Dissipation



Maximum Allowable Case Temperature